

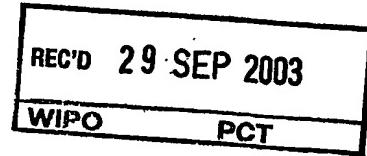


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Patentanmeldung Nr. Patent application No. Demande de brevet n°

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Power amplifier and method for power amplification

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Power amplifier and method for power amplification

The invention relates to a power amplifier and a method for power amplification in modern wireless and telecommunication systems.

Modern wireless and telecommunication systems require the power amplifier to operate in linear mode in order to maximize the spectral efficiency of the system.

- 5 However, linearity requirements conflict with efficiency requirements. Typically a linear power amplifier will be biased in class-B or class-AB and in order to reach the linearity specification will be backed off from its peak envelope power PEP of about 10dB. As a consequence, the power added efficiency PAE of the power amplifier will be compromised.

In power amplifiers for mobile communication the output power P_{out} is varying according to the communication requirements. The supply voltage, which is conventionally derived from a battery, is fixed to a certain value. The supply current I_{DC} will vary with the output power for amplifiers that are working in class-AB or B. The output current i_o of a class-AB or class-B is a truncated sinusoidal current. For a class-B, the conduction angle, i.e. the fraction of the sinusoid in which the power amplifier generates current is exactly equal to π , which means also $I_Q = 0$. For a class-AB the conduction angle is greater than π and therefore $I_Q > 0$. The supply current I_{DC} is always greater or equal to the quiescent current I_Q .

In conventional solutions V_{DC} is set to the maximum value allowed by the manufacturing technology, and it is provided via a supply generator (battery). The maximum power added efficiency PAE is reached at maximum output power. It can be shown that a power amplifier will show a power added efficiency lower than its maximal achievable when functioning at Output Power levels below the maximal ones.

In state-of-the-art mobile and wireless communication schemes the average output power of the power amplifier is set by the network in order to maximize the cell capacity. As a consequence, power amplifiers are not required to transmit continuously at maximum output power, but they are very often backed off to lower power levels (in(W-)CDMA systems usually 10dB lower). The power amplifier will show a lower power added efficiency and therefore a relatively higher power consumption. For example, it is

calculated that a power amplifier for a UMTS handset with power added efficiency $\text{PAE}_{\text{max}\%} = 35\%$ will show typically power added efficiency $\text{PAE} = 12\%$ at 10dB back-off.

The power amplifier output power is varied in order to adapt it to the communication requirement. In (W-)CDMA systems, for instance, the output power is varied in order to maximize cell-capacity. The base-station measures the received output power from the handset and sends commands to the handset to adjust the output power to a better value. This is called Power Control Loop, and an example of it can be found, for UMTS in ETSI: "UMTS TETRA standard", chapter TS 125.101, pages 11-13, ETSI 2001 and ETSI: "UMTS TETRA standard", chapter TS 125.214, pages 10-20, ETSI, 2001..

As the output power is varied the supply current I_{DC} will vary; namely, as the output power is decreased, the supply current will decrease. In fact, the conduction angle will increase and the current I_{DC} will tend to its minimum value I_Q . The variation of I_{DC} changes the performance of the active devices in the power amplifier, and brings to gain and linearity variation. At very low output power, the power dissipation will be independent on the output power level. In this situation the power stage is working as a class-A amplifier.

The high power dissipation of the power amplifier in modern mobile and wireless communication is affecting the performance of the communication equipment, especially mobile equipment such as mobile telephones and terminals. This dissipation has to be reduced.

In mobile communication and wireless systems the power amplifier is typically biased in class-AB. Class-B amplifiers are affected by cross-over problems and are not linear enough to comply with the linearity specification of communication standards. Class-A amplifiers are linear enough for the application but they dissipate far more than class-AB, therefore are not used. All the other classes of amplifiers are not linear enough for the standard, and require the adoption of complex linearisation techniques. Those techniques are not attractive for mobile equipment implementation.

The typical power amplifier for this kind of application is divided in a driver stage and a power stage. The driver stage could be composed of several cascaded stages. The two stages are connected via a matching network between them and via two other matching network to the input and the output. A Biasing block sets the quiescent current of both the driver and the power stage.

The power stage of the power amplifier is optimized for functioning at maximum output power, in which $I_{\text{DC}} > I_Q$. The linearity of the complete power amplifier is set to the minimum required by the specification, in order to get the maximum achievable

power added efficiency. When working at lower output power, I_{DC} decreases in the power stage. Because of this the gain, the input and the output impedance of the stage vary. These variation are usually partly compensated by correctly choosing the biasing of the driver stage such that the gain remain as constant as possible. In fact, as soon as the power stage will start to increase (expand) its gain, because of increasing I_{DC} , the driver stage will typically decrease (compress) the gain, so that gain flatness is achieved for a wide range of output power. Moreover, linearity of the power amplifier increases for lower output power up to level far beyond the standard requirements.

Fig. 1 shows a block diagram of a conventional power amplifier. Two stages, a driver stage 2 and a power stage 4 are connected via a matching network 6 between them and via two other matching networks 8 and 10 to the input and the output. A Biasing block 12 sets the quiescent current of both the driver and the power stage.

Fig. 2 shows a more detailed block diagram of the conventional power amplifier of Fig. 1 where the same reference numbers are used for the same items. The power amplifier, for example the power amplifier UAA3592 of PHILIPS SEMICONDUCTORS, consists of the power stage 4 and the driver stage 2 interconnected by the matching network 6. The input matching network 8 converts the input impedance of the driver stage 2 to the nominal impedance. The output matching network 10 maximizes the output power and removes the higher order components and is connected to an antenna 14. Two current biasing networks 13, 15 are providing a bias to the driver stage 2 and the power stage 4 respectively. A supply voltage V_{CC} is fed to the driver stage 2 and the power stage 4 through RF chokes 17, 19 respectively. The power amplifier has a 1dB compression point equal to -4dBm referred at the input power. Although a UAA3592 is taken as an example for the power amplifier, the considerations can be extended to any power amplifier operating in class AB for CDMA schemes.

Further bias circuits are to be found in the state of the art mentioned below.

The US-A-6,236,266 shows a bias circuit and bias supply method for a multistage power amplifier including heterojunction bipolar transistors for power amplifying a high frequency signal and suppressing an increase in Rx noise during low power output operation of the multistage power amplifier. The bias circuit outputs a control signal V_{APC} from an external control circuit to the base of only a first-stage amplifier HBT in the multistage power amplifier. To the base of the second and each later power amplifying stage

HBT of the multistage power amplifier, the bias circuit supplies a bias current regulated by voltage stabilizers according to the control signal V_{APC} . In the US-A-6,236,266 the quiescent current of the amplifier is varied according to the power level, this technique is, however, applied with the goal to reduce the noise in receiver unit.

5 The EP 0 734 118 A1 shows an active biasing circuit to provide linear operation of an RF power amplifier. A current generator circuit provides a current to the stages of the RF power amplifier. In the final power amplifier stage the current is applied to a bias control amplifier that includes a transistor connected as a diode. The transistor diode is connected through a resistor to the emitter of a bias control transistor, which is in turn
10 connected to and controls the gate of a transistor power amplifier in the final power amplifier stage of the RE power amplifier with a bias current that is the highest current level needed for highest RE power. The transistor diode and the current generator circuit are also connected to bias control transistors in the other stages of the RE power amplifier such that the other stages are likewise controlled with the current from the current generator. In the EP 0 734
15 118 A1 the goal is to maintain linear operation.

It is the object of the invention to provide a power amplifier and a method for power amplification wherein the power dissipation is drastically reduced, in particular in the
20 case of a class-AB power amplifier.

This object is achieved by a method for reducing power dissipation in a power amplifier used in wireless communication systems, said power amplifier having transistors showing a quiescent current, wherein the quiescent current of the power amplifier is adaptively changed according to the output average power of the power amplifier.

25 In an advantageous embodiment of the method of the invention, the adaptive biasing of the power amplifier having at least two stages, is done by changing the value of I_Q of at least one of stages of the power amplifier.

In an advantageous embodiment of the method of the invention, the adaptive biasing of the power amplifier having at least two stages, is done by changing the value of I_Q of all stages of the power amplifier.

30 In an advantageous embodiment of the method of the invention, the adaptive biasing of the power amplifier having at least two stages, is done by changing the value of I_Q of the power stage of the power amplifier.

In an advantageous embodiment of the method of the invention, the adaptive biasing of the power amplifier having at least two stages, is done by detecting the average output power of the power amplifier in an power detector and varying the value of I_Q of the two stages according to the detected power and a specified function an adaptive biasing network.

5

In an advantageous embodiment of the method of the invention, a voltage or current quantity proportional to the average output power is detected as average output power of the power amplifier.

10 In an advantageous embodiment of the method of the invention, a voltage or current quantity proportional to the average output power is detected in any of the stages of the power amplifier, preferably in a driver stage of the power amplifier.

In an advantageous embodiment of the method of the invention, the average output power is detected by applying a squaring function and averaging on a scaled copy of the collector current of the driver and/or power stage.

15 In an advantageous embodiment of the method of the invention, the averaging function is carried out directly after the squaring function in the power detector.

In an advantageous embodiment of the method of the invention, the averaging function is carried out in the adaptive biasing network.

20 The above object is achieved by a power amplifier for use in wireless communication systems, said power amplifier having transistors showing a quiescent current, comprising adaptive biasing means changing the quiescent current of the power amplifier according to the output average power of the power amplifier for reducing power dissipation in the power amplifier.

25 In a power amplifier comprising the adaptive biasing means, the dissipation is decreased and gain control is improved with respect to state-of-the-art solutions. The invention is based on adaptively changing the quiescent current of the power amplifier according to the output average power, i.e. changing the value of I_Q of at least one stage of the power amplifier. The invention has the following advantages when compared to state-of-the-art linear power amplifiers.

- 30
1. Reduced power amplifier dissipation (typically 70% reduction in dissipation).
 2. Full integration in the power amplifier - there is no need for external components.
 3. No need for additional pins.

4. Points 2 and 3 make the invention suitable for every handset without introducing changes in the architecture of the handset or in the layout of the PCB.

In a preferred embodiment of the power amplifier of the invention, the adaptive biasing means comprise a power detector detecting a quantity proportional the output power of the power amplifier and a adaptive biasing network.

5 In a preferred embodiment of the power amplifier of the invention, the power detector is configured to provide a squaring function and an averaging function on a quantity proportional the output power of the power amplifier.

10 In a preferred embodiment of the power amplifier of the invention, where the power amplifier comprises a driver stage, a current biasing network connected to the driver stage, an intermediate matching network, a power stage, and a current biasing network connected to the power stage, the power detector is connected to an input of the driver stage, and the adaptive biasing network is connected to the input of the power stage.

15 In a preferred embodiment of the power amplifier of the invention, the adaptive biasing network comprises a processing block connected to the power detector, and a current biasing network connected between the processing block and the input of the power stage.

20 In an embodiment of the power amplifier of the invention, the processing block comprises an analog/digital converter, a look-up table providing the function of changing the quiescent current of the power amplifier according to the output average power of the power amplifier, and a digital/analog converter.

25 In a preferred embodiment of the power amplifier of the invention, the processing block comprises a differential analog circuit implementing the function:

$$P_{DC}(I_Q) = \min I_Q(P_{DC}) \text{ with } \Delta G < \Delta G_{max} \text{ and spec (linearity)}$$

where ΔG is the gain variation and ΔG_{max} is the maximum gain variation allowed by the application, and the spec (linearity) is the linearity specification for the application.

30 In a preferred embodiment of the power amplifier of the invention, the processing block comprises an analog implementation circuit where a difference of $I_{pow} - I_{ref}$ is performed in the current domain and averaging is performed by a capacitor connected between a node carrying I_{pow} and ground.

The analog implementation of the invention does not introduces steps in the biasing of the power amplifier, and therefore gives continuity of operation.

In a preferred embodiment of the power amplifier of the invention, a diode stage is connected between a node carrying I_{pow} and ground.

In a preferred embodiment of the power amplifier of the invention, a resistor is connected between anode carrying I_{pow} and a mirror circuit provided at the output of the processing block and outputting I_{out} .

The above object is also achieved by an UMTS hand set comprising a power amplifier configured as stated above.

These and various other advantages and features of novelty which characterize the present invention are pointed out with particularity in the claims annexed hereto and forming a part hereof. However, for a better understanding of the invention, its advantages, and the object obtained by its use, reference should be made to the drawings which form a further part hereof, and to the accompanying descriptive matter in which there are illustrated and described preferred embodiments of the present invention.

15

Fig. 1 shows a block diagram of a conventional power amplifier.

Fig. 2 shows a more detailed block diagram of the conventional power amplifier of Fig. 1, for example the power amplifier UAA3592 of PHILIPS SEMICONDUCTORS.

20

Fig. 3 shows a block diagram of a power amplifier according to an embodiment of the invention.

Fig. 4 shows a more detailed block diagram of the power amplifier according to an embodiment of the invention as shown in Fig. 3.

Fig. 5 shows a circuit diagram of a differential implementation of the power detector used in the power amplifier according to an embodiment of the invention as shown in Fig. 4.

Fig. 6 shows a block diagram of a digital implementation of the adaptive biasing network shown in Fig. 4.

Fig. 7 shows, in the analog domain, an analog implementation of the adaptive biasing network shown in Fig. 4.

Fig. 8 shows, in the current domain, an analog implementation of the adaptive biasing network shown in Fig. 4.

Fig. 9 shows a simulated I_Q for the sliding biasing according to the invention and conventional biasing for a UMTS power amplifier.

Fig. 10 shows a simulated IM3 for the sliding biasing according to the invention and conventional biasing for a UMTS power amplifier.

Fig. 11 shows a simulated power dissipation versus output power for the sliding biasing according to the invention and conventional biasing for a UMTS power amplifier.

Fig. 3 again shows a power amplifier having, the driver stage 2 and the power stage 4 which are connected via a matching network 6 between them and via the two matching networks 8 and 10 to the input and the output and to the antenna 14. The adaptive biasing means of the invention comprise a power detector 16 and an adaptive biasing circuit 18. The power detector 16 detects the average output power of the power amplifier and feeds it to the adaptive biasing circuit 18. The adaptive biasing circuit 18 varies the value of I_Q of the two stages 2,4 according to the detected power and a specified function. According to Fig. 3, the power detector senses the power at the output of the driver stage 2. However this sensing could be performed in any part of the power amplifier (input of the driver stage 2, output of the driver stage 2, input of the power stage 4, output of the power stage 4); what is important is to produce a quantity (voltage or current) proportional to the average output power.

In order to avoid clipping and/or crossover effect to reduce the accuracy of the power detector 16, it is advantageous to perform the power sensing in nodes in which the signals are fully sinusoidal; therefore it is recommendable to perform the sensing in the driver stage, which is mostly acting as a class-A.

Fig. 4 shows the schematic of a linear power amplifier for UMTS with adaptative biasing with sliding biasing current using the adaptive biasing means 16, 18 driven by the input power. Basically the RF power is read at the input of the power amplifier. Then the RF power controls quiescent current of the power stage 4. The adaptive biasing means controlled by the RF power has been divided in three sub-logical blocks: power detector 16, offset eraser 20 and processing block 22. In this embodiment, the power detector 18 is connected to the input of the driver stage 2. The offset eraser is connected between the current biasing network 13 and the processing block 22. The processing block is connected to the offset eraser 20 and to the power detector 18 and, furthermore, via the current biasing network 15 to the input of the power stage 4. The current biasing network 15 receives a signal

I_{SLID} (P_{in}) which is a sliding biasing current depending on the input power, and feeds the power stage 4.

The power detector 16 produces a DC current proportional to the RF power, the offset eraser 20 cancels the DC offset of the power detector 16 due to the biasing and the processing block 22 performs filtering, integration and clipping function. In order to implement sliding biasing, it is needed to know the RF input or output power of the power amplifier. The RF power is sensed at the input of the power stage 2 (Fig. 4). This information is transformed by the power detector 16 into a current. The following processing block 19 awaits to process this current.

The best way to implement a power detector 16 is utilizing a squaring function and averaging on a scaled copy of the collector current of the driver and/or power stage as shown in Fig. 5. To put the averaging function directly after the squaring function is possible but not needed. Averaging could be done also in the adaptive biasing circuit.

Fig. 5 shows a more detailed circuit of the power detector 16 in the power amplifier environment. A reference current I_{ref} is fed via a squaring circuit 26 to a transistor Q3 the base of which is connected to the base of a transistor Q1 which is fed by I_{bias} . A further transistor Q4 is connected between I_{bias} and via a resistor R1 to the base of the transistor Q1. The resistor is connected via an inductance 28 to a resistor R2 which is connected via a capacitance 30 a terminal carrying RF_{in} . The node between the resistor R2 and the capacitance 30 is connected to the base of a transistor Q0. The collector of the transistor Q0 is connected to a terminal carrying RF_{out} . The base of the transistor Q0 is connected to the base of a transistor Q2, the collector of which transistor is connected to a further squaring circuit 32 which outputs I_{sq} .

According to Fig. 5, the strategy to sense the RF and quiescent current. The RF current is sensed directly on the base of the driver BJT(Q0). In order to compensate the offset created by the I_{DC} of the driver stage, the quiescent level is detected on the biasing network by Q3. Duplicating the circuit of the power detector 16 to implement the offset eraser 20 permits to compensate the temperature variations. As this offset eraser 20 is fed only with the quiescent component portion of the driver BJT, it compensates the offset created by I_{CQ1-Q} . The bipolar Q2 senses the RF signal, while Q3 detects only the portion of the quiescent current. Actually the inductor interrupts the RF path and consequently it ensures a decoupling between bias and RF circuits. The offset compensation can be performed by means of an independent current reference. This solution seems to be more easy to implement but the temperature changes in the power amplifier and tolerance

introduced by the power detector will not be compensated. To adopt a copy of power detector permits partially to compensate these variations.

In order to counteract temperature variations and DC-offset a differential approach can be used in the power detector. Fig. 5 shows the differential implementation of the power detector. The RF power transistor is transistor Q0. The current I_{bias} is mirrored by the transistor pair Q1-Q0 to transistor Q0. The quiescent current of transistor Q0 will be equal to:

$$I_{Q0} = I_{bias} \times A_0 / A_1 = m \times I_{bias}, \quad (1)$$

10

where A_0 and A_1 are respectively the emitter area of transistor Q0 and transistor Q1. The collector current of transistor Q0 is mirrored into transistor Q2. Transistor Q2 is chosen to be smaller than transistor Q0. In order to reduce power dissipation, transistor Q2 senses the current of transistor Q0 according to the equation:

15

$$I_{c2} = I_{c0} \times A_2 / A_0 = 1/n \times I_{c0}, \quad (2)$$

where I_{c0} and I_{c2} are the collector currents of transistor Q0 and transistor Q2, respectively, and n is the ratio between the emitter areas of transistor Q2 and transistor Q0. Because of this the quiescent current of transistor Q2 will be proportional to the quiescent current of transistor Q0, transistor transistor Q3 does not receive RF signal at its base, because of the filtering effect of the inductance; therefore its collector current is constant and proportional to I_{bias} . If the emitter area ratio transistor Q3 to transistor Q1 is properly chosen, than the collector current of transistor Q3 will be equal to the quiescent current of transistor Q2. Therefore:

$$I_{c3} = A_3 / A_1 \times I_{bias} = A_3 / A_1 \times n/m \times I_{c2} \quad (3)$$

$$\text{If } A_3 / A_2 = n/m = A_2 / A_1 \text{ then } I_{c3} = I_{c2} \quad (4)$$

30

The additional sensing transistor Q3 is used to compensate for temperature and biasing effects and cancel the I_Q -term from the output.

The collector currents of transistor Q1 and transistor Q3 will be squared, averaged and subtracted or, alternatively, squared, subtracted and averaged resulting in I_{SQ} . Subtracting

$$5 \quad I_{SQ} = I_{C2}^2 = 1/n^2 \times (I_Q^2 + I_0^2/2 - I_0^2/2 \cos(4\pi f t)) \quad (5)$$

from

$$I_{ref} = I_{C1}^2 = I_Q^2/n^2 \quad (6)$$

While neglecting the high-frequency terms one gets an output current:

$$10 \quad I_{pow} = I_{SQ} - I_{ref} = I_0^2/2n^2 \quad (7)$$

I_{pow} is directly proportional to the square amplitude of the current of the amplified signal and therefore to the average power. Since the quiescent current term does not appear in equation 7, the sliding biasing technique can be applied also to the same transistor on which the sensing is performed; in fact, what is controlled (the quiescent current) is not present in the sensed quantity (power indicator I_{pow}). In this way there is no risk of oscillation, which will be present in the case that the controlled quantity I_Q will be present also in the sensed quantity.

20 In equation 5 it is assumed that the sensed amplifier works in class-A, i.e. that the sensed current has a perfect sinusoidal shape. Even though this assumption is not general, in order to reduce distortion effects and dissipation sensing is likely to occur at the output of the driver stage, which is mostly a class-A. Moreover, if the driver stage is a class-AB, the power sensing it is likely to be needed only in a limited range of output power (and surely in 25 back-off from the maximum power) this is expressed in equations 9a – 9c by the parameters P_1 and P_2 . In this conditions the driver stage is likely to work in class-A or very close to class-A, so that equation 5 represents an appropriate approximation.

In equations 5 and 6 it is assumed that the squaring function is perfect. This is not necessary, and squaring circuit having low accuracy can be used as well. In fact, the high-30 frequency tones will be eliminated by the averaging and the effect of the quiescent current will be eliminated by the cancellation. Ultimately the important thing is to have a monotone (Bi-univocal) function of the output power.

The goal of the adaptive biasing circuit is to generate an optimal I_Q for the power amplifier with respect to the average output power. Therefore this block must function

such that the dissipated power is at minimum with the linearity and gain variation constraint imposed, that is:

$$P_{DC}(I_Q) = \min I_Q(P_{DC}) \quad (8)$$

5

With $\Delta G < \Delta G_{max}$ and spec (linearity) where ΔG is the gain variation and ΔG_{max} is the maximum gain variation allowed by the application, and the spec (linearity) is the linearity specification for the application. This specification is usually in term of ACLR and/or EVM but could be every linearity specification. In case of ACLR specification it could be useful to translate it into IM3 specification. The chosen function depends therefore on the type of power amplifier and on the application chosen.

The choice of the optimal adaptive I_Q is strongly dependent on the application constraints. At very low power a conventional linear power amplifier is far more linear than required from the specifications. In this operating region the power amplifier acts as a class-A, and its IM3 (3rd order inter-modulation product) will be very low. The IM3 is dictating the linearity performance of linear power amplifiers. The IM3, for a linear power amplifier, decreases with 2dB/dB slope with decreasing power, when backing off far from the 1dB compression point.

One could think to decrease I_Q up to a value reaching the minimum IM3 allowed from the standard. However, at very low power, variation on the gain are important. Decreasing I_Q from its optimal value to a lower value, can also bring about gain variation. In WCDMA standards (like UMTS), the gain variation should always be kept below a certain value, typically $\Delta G_{max} = 1\text{dB}$. This represents the main constraint in the choice of the function $I_Q = I_Q(P_{out})$ at low P_{out} .

The consequences on power dissipation when a lower I_Q is chosen, are that the DC collector current I_{DC} starts to increase for output power higher than 0 dBm. However, in low-quiescent current operation, the relative variation is much stronger. For the lower I_Q values a gain variation is observed around $P_{out} = 0\text{ dBm}$. For an output power higher than 20 dBm, I_{DC} is not strongly influenced by the choice of I_Q .

30

$I_Q = I_Q(P_{out})$ is chosen as follows:

- a) for low power: choose I_Q as the minimum current allowing a gain variation smaller than the maximum allowed,
- b) for intermediate power: vary I_Q such that the linearity constraint is respected (typically IM3),

- c) for high power: choose I_Q to the nominal value, since it won't affect the dissipation.

5 The implementation of this function could be done in the digital domain via a analog/digital converter ADC, a look-up table LUT and a digital/analog converter DAC as illustrated in Fig. 6. The analog/digital converter ADC digitizes the output of the power detector and pass it to a look-up table which computes the correct value of quiescent current. This value will be passed to the digital/analog converter DAC to be converted into the actual I_Q (or a scaled version of it) to be fed to the biasing networks.

10 In the analog implementation of the adaptive biasing circuit, an analog block has to implement the function $I_Q = I_Q(P_{out})$ as in formula 10. The quantity P_{out} is fed to the circuit via a voltage or a current generated by the power detector. The analog implementation is to be preferred to the digital implementation because, in the digital implementation, quantization noise on the quiescent current could introduce disturbances into the RF signal.

15 A possible implementation of the function could be as expressed as follows:

$$I_Q = I_{Q1} \quad P_{out} \leq P_1 \quad (9a)$$

$$I_Q = \frac{(I_{Q2} - I_{Q1}) P_{out} + I_{Q1} P_2 - I_{Q2} P_1}{P_2 - P_1} \quad \text{for } P_1 < P_{out} \leq P_2 \quad (9b)$$

$$I_Q = I_{Q2} \quad P_{out} > P_2 \quad (9c)$$

20

These equations state that for output power lower than a level P_1 the quiescent current should be set to the value I_{Q1} . For output power larger than P_2 than the quiescent current should be set to I_{Q2} . For intermediate values the quiescent current should be set to intermediate values. The function expressed in equations 9a – 9c has the advantage of being 25 extremely simple and of easy implementation. It should be noted that, most presumably, for lower output power the quiescent current can be kept small. Therefore $I_{Q1} < I_{Q2}$. One can conclude that the saved power, at low output power levels, is given by the quantity:

$$P_{saved} = V_{DC} (I_{Q2} - I_{Q1}) \quad (10)$$

30

An implementation in the analog domain is presented in Fig. 7. The resistors R2,1 and RR2,2 and the capacitors C1 and C2 implement the averaging function, removing the high-frequency content of the current I_{sq} and I_{ref} (since I_{ref} should not have high-frequency content the capacitor on its branch could be removed). Resistors R2,1 and R2,2 convert the

low-frequency content of the currents I_{sq} and I_{ref} into a voltage $V = R_2 (I_{sq} - I_{ref})$. This voltage is then reconverted to a current by the differential power amplifier. The biasing current I_{bias} is fed via two resistors $R_{1,1}$ and $R_{1,2}$ to the emitters of transistors T1 and T2 which are connected to the nodes between the capacitor C1 and the resistor $R_{2,1}$ and the node between the capacitor C2 and the resistor $R_{2,2}$ respectively. The collectors of the transistors T1 and T2 are carrying I_{out+} and I_{out-} respectively. I_{sq} is output from $R_{2,1}$ and I_{ref} is fed to $R_{2,2}$.

$$I_{out} = I_{out+} - I_{out-} = R_2/2R_1 (I_{sq} - I_{ref}) \quad (11)$$

10 Equation 11 holds until the output current not larger than the biasing current of the differential power amplifier, that is $I_{out} \leq I_B$.

The behavior of this circuit can be analyzed with respect to equations 9a – 9c as follows. At very low power the RF signal will not be able to generate an additional DC current into the transistor Q2 in Fig. 5. Therefore:

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$$I_{c2} = I_{c3} \quad I_{sq} = I_{ref} \quad I_{out} = 0. \quad (12)$$

At intermediate power:

$$I_{c2} > I_{c3} \quad I_{sq} - I_{ref} = I_{pow} > 0 \quad I_{out} = R_2/2R_1 \times I_{pow} \quad (13)$$

20 At very high power the differential pair will saturate, and

$$I_{out} = I_B. \quad (14)$$

The equations 11 – 14, unless an additional constant, perfectly implement equation

$$V_{DC} = V_{max}. \quad (15)$$

25

An implementation the processing block 22 in the current domain of the adaptive biasing circuit is presented in Fig. 8. The difference $I_{pow} = I_{sq} - I_{ref}$ is performed in the current domain, before averaging, which is performed by the capacitor C connected between node A (V1) and ground. The output current is equal to the low-power amplifiers filtered version of I_{pow} , as desired. The clipping at high levels is performed by the resistor R and three diodes D1 to D3 connected between node A (V1) and ground. In fact the maximum output current is reached when the voltage at the node A is maximum, i.e $V_A = 3 V_D$. In this case the current flowing through the resistor R will be equal to $I_R = (3V_D - V_B)/R$, being V_B the voltage at the input of the current mirror, which can be assumed constant.

The circuit of Fig. 8 has two inputs I_{sq} and I_{ref} and one output I_{out} . I_{sq} comes from the power detector. The input I_{ref} comes from the reference circuit and it avails to erase the offset contained in I_{sq} . The diodes D1 to D3 are to clip the current as the nominal current level is reached. Above a certain output power, V_1 is large enough to permit the diodes to conduct. So the saturation of the output current I_{out} starts, and excess I_{det} flows through the diodes D1 to D3. The I_{RF} contained in I_{sq} is removed by the capacitor C. The capacitor C carries out two functions: filtering of the RF signal and with the resistor R integrating the DC current related to the RF power. So only I_{det} is able to pass through resistor R and is then mirrored by the current mirror 40 in the output branch. As the power RF increases, I_{det} increases as well. Consequently also V_1 at node A increases and V_2 at node B remains constant.

In Fig. 9 the simulated I_Q as implemented by the circuit presented in Fig. 8 is presented. This implementation allows a gain variation smaller than 1dB ($\Delta G \leq \Delta G_{max} = 1$ dB). The consequences on linearity are shown in Fig. 10. It is possible to notice that, even if the IM3 is larger than the one in the conventional solution, we are still far below the required IM3. In order to estimate the reduction in power dissipation due to the technique, P_{out} probability distributions of the (W-)CDMA schemes should be taken into account as explained in [6]. With the power probability distribution taken into account, this method is causing a reduction in power consumption up to 70%.

Fig. 9 shows the quiescent current in the power stage in mA versus the output power in dBm in case of conventional biasing and sliding biasing. Since the quiescent current determines the dissipation in back off condition and for a large portion of the time the power amplifier will operate in this region, Fig. 9 shows implicitly a drastic reduction of the power dissipation. The quiescent current actually has been decreased by 3.5 times.

Fig. 10 shows IM3 in dBc versus the output power dBm in case of conventional and sliding biasing. With the choice of the minimum quiescent current starting from very low RF power the course of the IM3 curve will be parallel to the IM3 curve of the conventional power amplifier, but will stay above it. It is worth noting that the sliding biasing acts so that the linearity specification of the UMTS standard are fulfilled.

Both curves have been obtained by supplying the power stage with the quiescent currents. The sliding current has been chosen so that the IM3 curve of the sliding power amplifier is below the IM3 threshold for UMTS requirements in back-off condition. As the RF power is increased IM3 exceeds the -40 dBc threshold. In this region the current is increased in order to recover the linearity and overcome to fail in reaching the

specification. Over the range between OdBm and 15dBm there is a compensation between gain flatness and signal level, this is why the Δ IM3 remains almost constant.

In the range beyond 20 dBm the conventional level of quiescent current of the power stage is restored. In fact in this sector the DC current of the power stage does not depend anymore on the quiescent current, providing no advantage in the holding of a low bias point in term of power saving. Then the IM3 curve of the sliding power amplifier overlaps the conventional power amplifier curve and the power amplifier will be able to deliver the maximum power with the necessary linearity. Sliding biasing has been carried out according to the biasing curve described by Fig. 9.

Fig. 11 shows the power dissipation in mW versus output power in dBm in the case of sliding and conventional biasing for the UAA3592 power amplifier. The DC power dissipation has been reduced up to one third in deep back off, i.e. the sliding biasing impact on the power consumption. The phone power distribution can be interpreted as a weighting function of the DC power dissipation shown in Fig. 11. Since the power amplifier spends 80% of the time for $P_{out} < 15\text{dB}$ and being the DC power consumption in this region strongly reduced as the quiescent current is decreased which means that the sliding biasing technique is suitable to improve the consumption performance of the power amplifier. Furthermore, it has been verified that additional circuitry for the sliding biasing dissipates less than 1m W. Hence it does not spoil the power saving of the power amplifier.

The proposed invention, with the power detector in a MOS form, implemented in a differential way as described in Fig. 5 and the adaptive biasing circuit as presented in Fig. 8 is under implementation for a UMTS power amplifier where the design is based on the UAA3592. The simulation results show feasibility of the invention and achieved results.

The invention can be applied to all class-A and class-AB power amplifiers working with a range of different output power. At this moment an implementation is carried on for a UMTS power amplifier. However the invention can be successfully implemented for all the mobile communication standards (e.g. EDGE, UMTS, CDMA, W-CDMA, TD-SCDMA) and wireless standards requiring linearity of the power amplifier. The invention can applied to Bipolar and/or (MOS)FET power amplifiers, independently on the technology they use (Si, SiGe, GaAs, InP). All circuit presented in the application are in a BJT format but they can easily implemented in a MOSFET way.

New characteristics and advantages of the invention covered by this document have been set forth in the foregoing description. It will be understood, however, that this disclosure is, in many respects, only illustrative. Changes may be made in details, particularly

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in matters of shape, size, and arrangement of parts, without exceeding the scope of the invention. The scope of the invention is, of course, defined in the language in which the appended claims are expressed.

CLAIMS:

1. Method for reducing power dissipation in a power amplifier used in wireless communication systems, said power amplifier having transistors showing a quiescent current, wherein the quiescent current of the power amplifier is adaptively changed according to the output average power of the power amplifier.

5 .

2. The method of claim 1, wherein the adaptive biasing of the power amplifier having at least two stages, is done by changing the value of I_Q of at least one of stages of the power amplifier.

10 3. The method of claim 1, wherein the adaptive biasing of the power amplifier having at least two stages, is done by changing the value of I_Q of all stages of the power amplifier.

15 4. The method of claim 1, wherein the adaptive biasing of the power amplifier having at least two stages, is done by changing the value of I_Q of the power stage of the power amplifier.

20 5. The method of any of the claims 1 to 4, wherein the adaptive biasing of the power amplifier having at least two stages, is done by detecting the average output power of the power amplifier in an power detector and varying the value of I_Q of the two stages according to the detected power and a specified function an adaptive biasing circuit.

25 6. The method of any of the claims 1 to 5, wherein a voltage or current quantity proportional to the average output power is detected as average output power of the power amplifier.

7. The method of any of the claims 1 to 6, wherein a voltage or current quantity proportional to the average output power is detected in any of the stages of the power amplifier, preferably in a driver stage of the power amplifier.

8. The method of claim 5, wherein the average output power is detected by applying a squaring function and averaging on a scaled copy of the collector current of the driver and/or power stage.

5

9. The method of claim 8, wherein the averaging function is carried out directly after the squaring function in the power detector.

10. The method of claim 8, wherein the averaging function is carried out in the adaptive biasing circuit.

11. A power amplifier for use in wireless communication systems, said power amplifier having transistors showing a quiescent current, comprising adaptive biasing means changing the quiescent current of the power amplifier according to the output average power of the power amplifier for reducing power dissipation in the power amplifier.

12. The power amplifier of claim 11, wherein the adaptive biasing means comprise a power detector detecting a quantity proportional the output power of the power amplifier and a adaptive biasing circuit.

20

13. The power amplifier of claim 12, wherein the power detector is configured to provide a squaring function and an averaging function on a quantity proportional the output power of the power amplifier.

25 14. The power amplifier of claim 12, comprising a driver stage, a current biasing network connected to the driver stage, an intermediate matching network, a power stage, and a current biasing network connected to the power stage, wherein the power detector is connected to an input of the driver stage, and the adaptive biasing circuit is connected to the input of the power stage.

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15. The power amplifier of claim 12, wherein the adaptive biasing circuit comprises a processing block connected to the power detector, and a current biasing network connected between the processing block and the input of the power stage.

16. The power amplifier of claim 15, wherein the processing block comprises an analog/digital converter, a look-up table providing the function of changing the quiescent current of the power amplifier according to the output average power of the power amplifier, and a digital/analog converter.

5

17. The power amplifier of claim 15, wherein the processing block comprises a differential analog circuit implementing the function:

$$P_{DC}(I_Q) = \min I_Q(P_{DC}) \text{ with } \Delta G < \Delta G_{max} \text{ and spec (linearity)}$$

10

where ΔG is the gain variation and ΔG_{max} is the maximum gain variation allowed by the application, and the spec (linearity) is the linearity specification for the application

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18. The power amplifier of claim 15, wherein the processing block comprises an analog implementation circuit where a difference of $I_{pow} = I_{sq} - I_{ref}$ is performed in the current domain and averaging is performed by a capacitor connected between a node carrying I_{pow} and ground.

20

19. The power amplifier of claim 18, wherein a diode stage is connected between a node carrying I_{pow} and ground.

25

20. The power amplifier of claim 18, wherein a resistor is connected between anode carrying I_{pow} and a mirror circuit provided at the output of the processing block and outputting I_{out} .

21. An UMTS hand set comprising a power amplifier configured as claimed in any of the claims 11 to 20.

ABSTRACT:

The invention provides a method for reducing power dissipation in a power amplifier used in wireless communication systems, said power amplifier having transistors showing a quiescent current, wherein the quiescent current of the power amplifier is adaptively changed according to the output average power of the power amplifier. A power amplifier for use in wireless communication systems is provided, said power amplifier having transistors showing a quiescent current, comprising adaptive biasing means changing the quiescent current of the power amplifier according to the output average power of the power amplifier for reducing power dissipation in the power amplifier. An UMTS hand set comprises a power amplifier as specified above.

10

Fig. 3

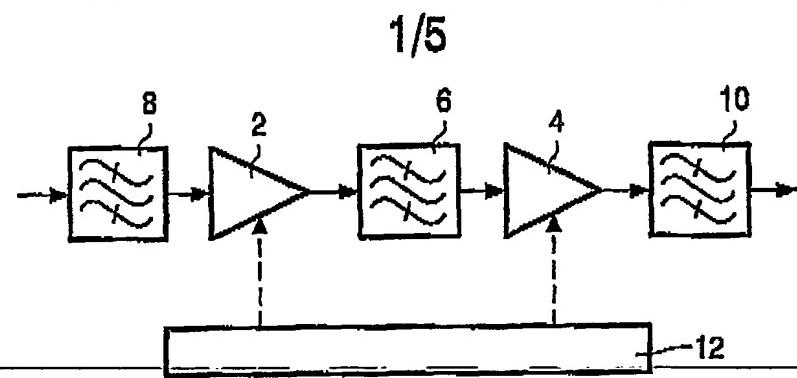


FIG. 1

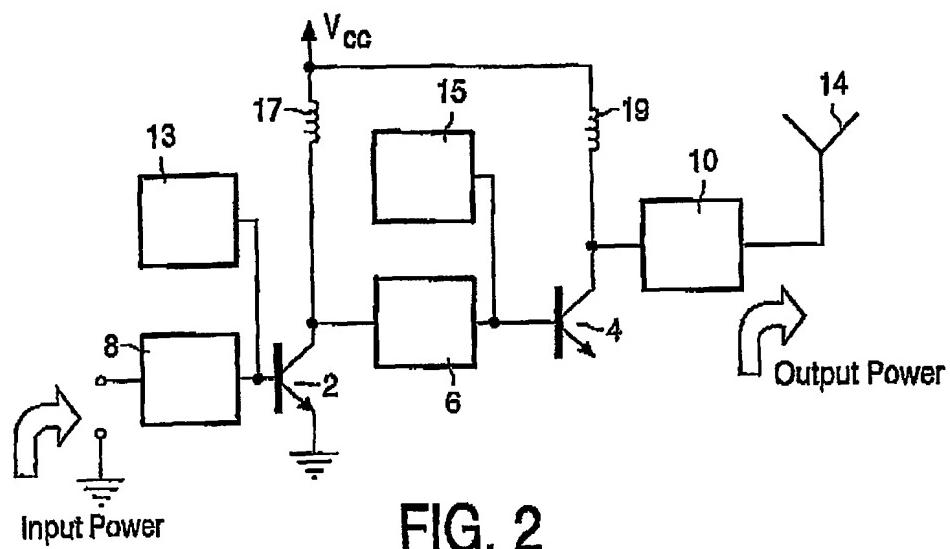


FIG. 2

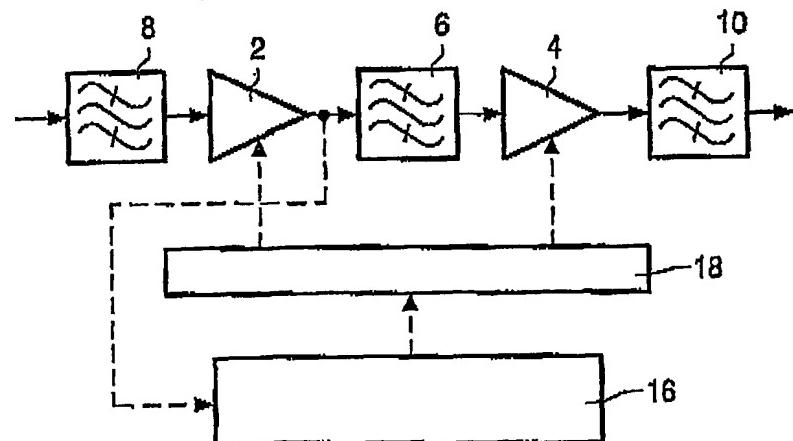


FIG. 3

2/5

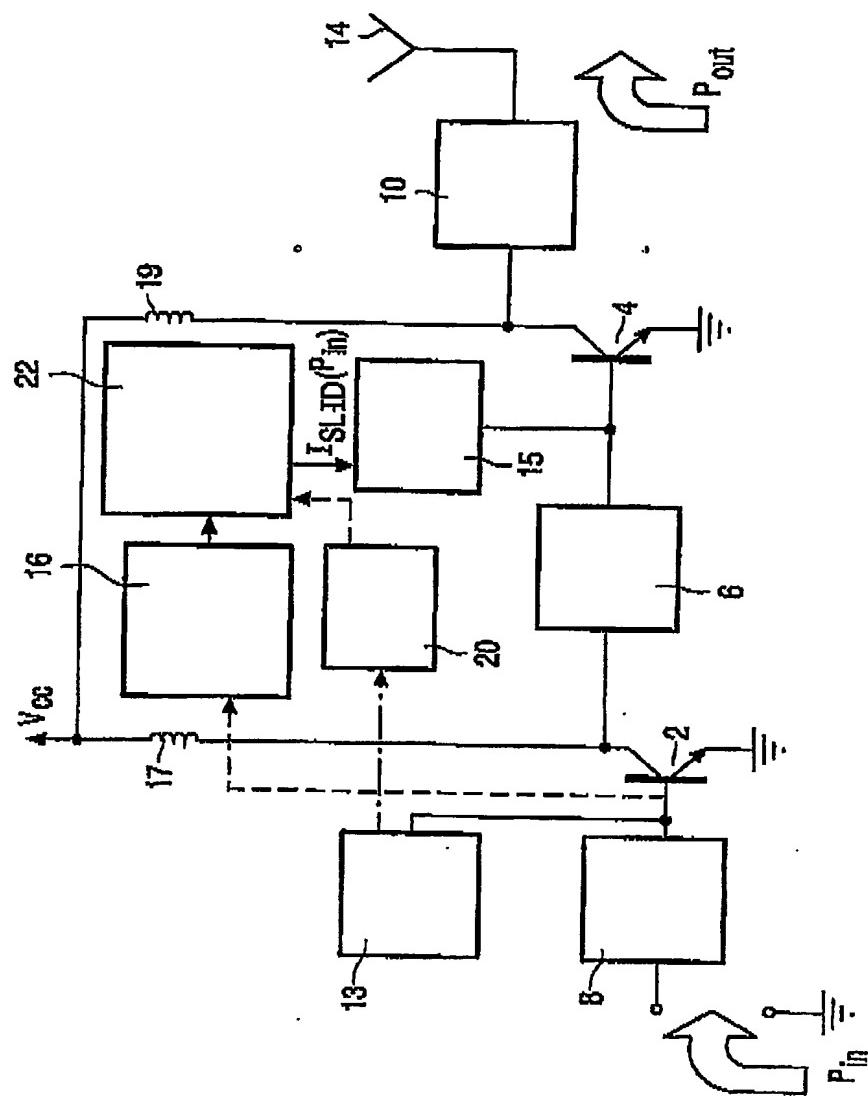


FIG. 4

3/5

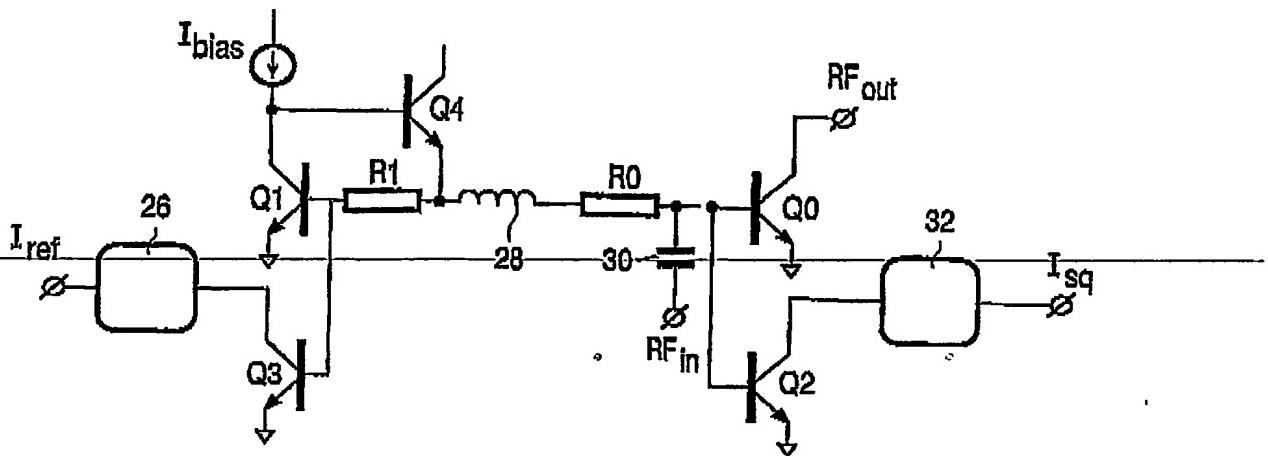


FIG. 5

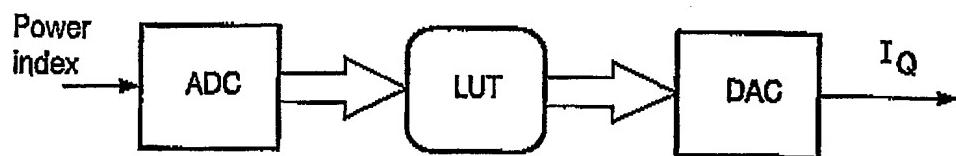


FIG. 6

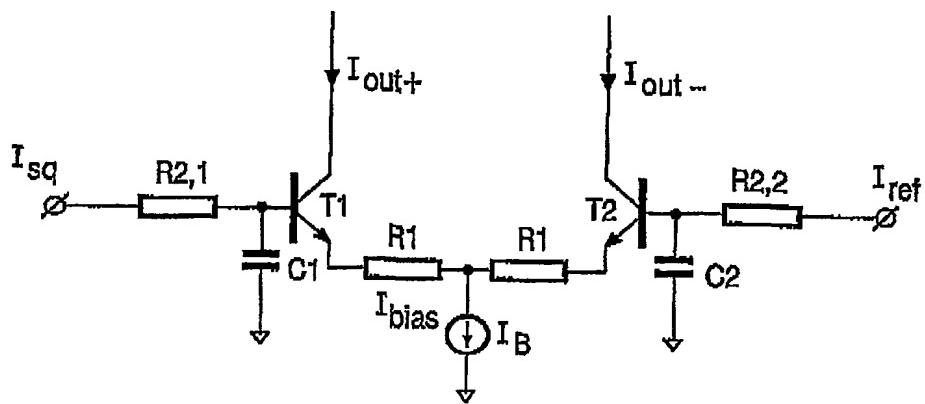


FIG. 7

4/5

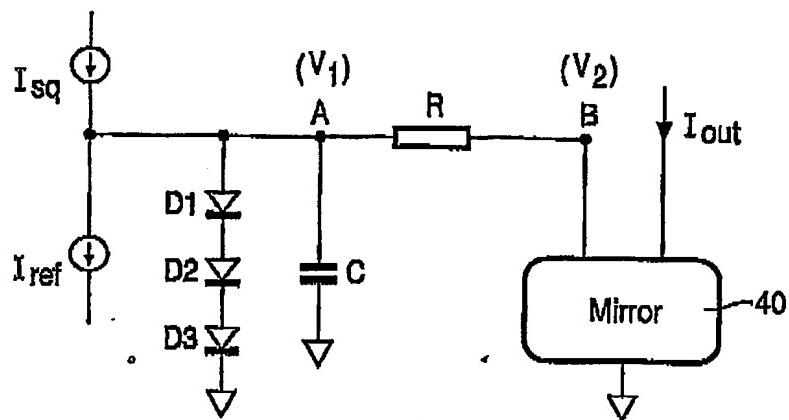


FIG. 8

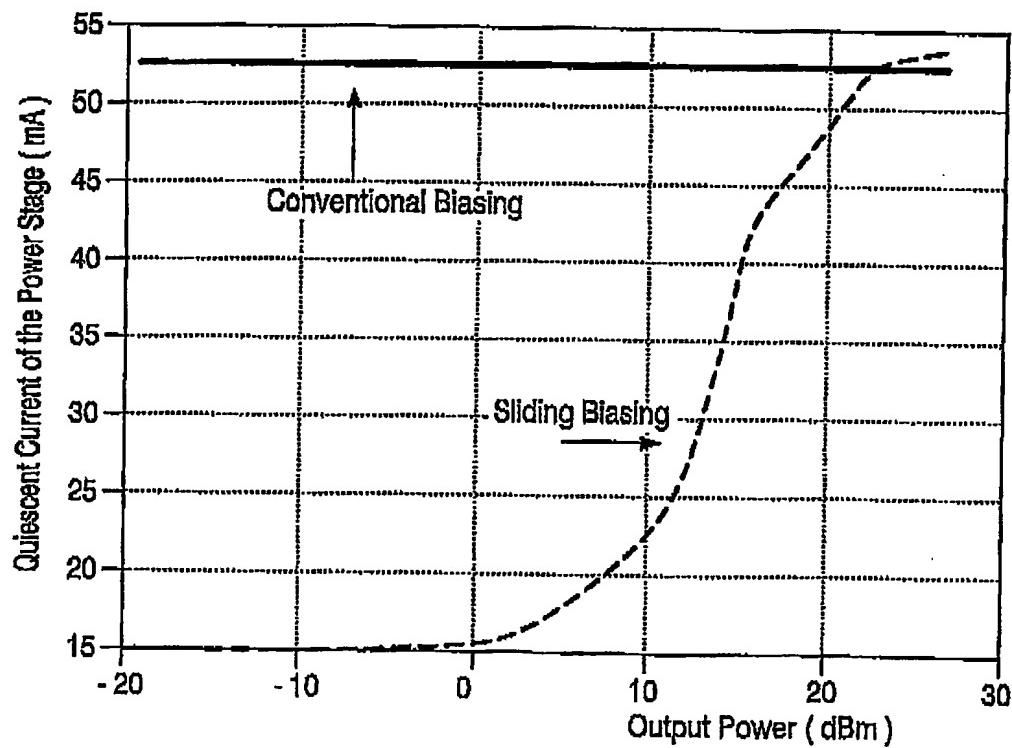


FIG. 9

5/5

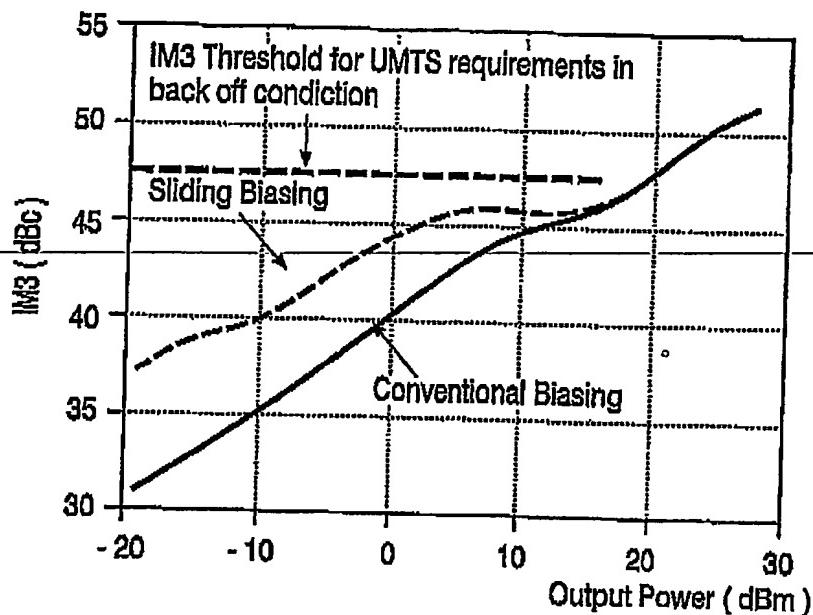


FIG. 10

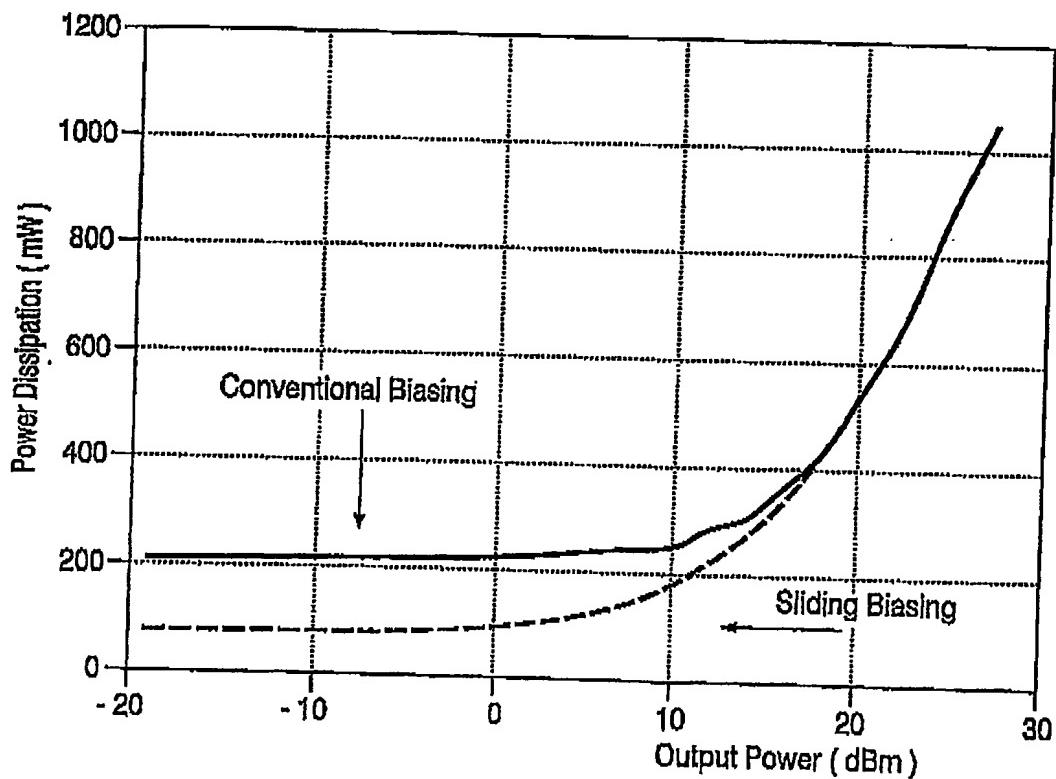


FIG. 11

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